


	<p><b>IPI09N03LA</b></p>
	<p><b>Hersteller-Teilenummer:</b> IPI09N03LA</p> <p><b>Hersteller / Marke:</b> International Rectifier (Infineon Technologies)</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 25V 50A I2PAK</p> <p><b>Datenblätter:</b>  IPI09N03LA.pdf</p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 2000 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	IPI09N03LA
Hersteller	International Rectifier (Infineon Technologies)
Beschreibung	MOSFET N-CH 25V 50A I2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	2000 pcs Stock
Serie	OptiMOS™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-262-3 Long Leads, I <sup>2</sup> Pak, TO-262AA
Supplier Device-Gehäuse	PG-TO262-3
Verlustleistung (max)	63W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	25V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	50A (Tc)
Rds On (Max) @ Id, Vgs	9.2 mOhm @ 30A, 10V
VGS (th) (Max) @ Id	2V @ 20µA
Gate Charge (Qg) (Max) @ Vgs	13nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	1642pF @ 15V
Verpackung	Tube

IPI09N03LA ist neu im Original, Suche IPI09N03LA Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IPI09N03LA International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage IPI09N03LA: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>IPI086N10N3GXKSA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 100V 80A TO262-3</p>	 <p><b>IPI08CN10N G</b> International Rectifier (Infineon Technologies) MOSFET N-CH 100V 95A TO262-3</p>	 <p><b>IPI086N10N3G</b> Original IPI086N10N3G Original</p>	 <p><b>IPI100N04S4H2AKSA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 40V 100A TO262-3-1</p>
 <p><b>IPI100N04S303AKSA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 40V 100A TO262-3</p>	 <p><b>IPI08CN10N</b> INFINEON IPI08CN10N INFINEON</p>	 <p><b>IPI100N04S3-03</b> International Rectifier (Infineon Technologies) IPI100N04S3-03 infineon/</p>	 <p><b>IPI100N06S3-03</b> International Rectifier (Infineon Technologies) MOSFET N-CH 55V 100A I2PAK</p>

heiße Teile

Mehr

- |                  |                   |                  |                  |                    |
|------------------|-------------------|------------------|------------------|--------------------|
| ⊕ 0402ZD475MAT2A | ↔ 0805ZC563JAT2A  | ⇒ 6DI100MA-050   | D AD8036ARZ      | ↔ HFA04TB60SPBF    |
| ⊖ IPI037N06L3G   | ⊕ IPI040N06N3G    | D IPI041N12N3G   | ⇒ IPI057N08N3G   | ↔ IPI075N15N3      |
| ⊕ IPI076N12N3G   | ⊖ IPI086N10N3G    | ⊕ IPI100N04S3-03 | ↔ IPI120N04S4-01 | ↔ IPI120N04S4-02   |
| D IPI120N06S4-02 | ⊕ IPI120N06S4-03  | ⊖ IPI120N06S4-H1 | ⊕ IPI120P04P4-04 | ↔ IPI120P04P4L-03  |
| ⇒ IPI126N10N3G   | ↔ IPI12CN10NG     | ⊕ IPI139N08N3G   | ⊖ IPI16CN10NG    | ↔ IPI26CN10NG      |
| ↔ IPI50CN10NG    | ⇒ IPI50R199CP     | D IPI50R250CP    | ⊕ IPI50R299CP    | ⊖ IPI50R399CP      |
| ⊕ IPI600N25N3G   | D IPI60R199CP     | ⇒ IPI60R250CP    | ↔ IPI60R299CP    | ↔ IPI60R380C6      |
| ⊖ IPI60R520CP    | ⊕ IPI65R099C6     | ↔ IPI65R190CFD   | ⇒ IPI65R600C6    | ↔ IPI80N04S3-03    |
| ⊕ IPI80N06S4-07  | ⊖ IPI90N04S4-02T  | ⊕ IPI90R1K2C3    | D IRF3805SPBF    | ↔ IRF7413QTRPBF    |
| ↔ MIC94070YMT-TR | ⊕ P6KE440CA-E3/73 | ⊖ SBRF2080CT     | ⊕ VHF36-08I05    | ↔ VLS252010CX-1R0M |

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